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Team Nexperia



IP4786CZ32

**DVI and HDMI interface ESD and overcurrent protection,
DDC/CEC buffering, hot plug detect and backdrive protection**

Rev. 5 — 24 June 2014

Product data sheet

1. Product profile

1.1 General description

The IP4786CZ32 is designed to protect High-Definition Multimedia Interface (HDMI) transmitter host interfaces. It includes HDMI 5 V overcurrent / overvoltage protection, Display Data Channel (DDC) buffering and decoupling, hot plug detect, backdrive protection, Consumer Electronic Control (CEC) buffering and decoupling, and ± 12 kV contact ElectroStatic Discharge (ESD) protection for all I/Os, exceeding the IEC 61000-4-2 level 4 standard.

The IP4786CZ32 incorporates Transmission Line Clamping (TLC) technology on the high-speed Transition Minimized Differential Signaling (TMDS) lines to simplify routing and help reduce impedance discontinuities. All TMDS lines are protected by an impedance-matched diode configuration that minimizes impedance discontinuities caused by typical shunt diodes.

The enhanced 60 mA overcurrent / overvoltage linear regulator guarantees HDMI-compliant 5 V output voltage levels with up to 6.5 V inputs.

The DDC lines use a new buffering concept which decouples the internal capacitive load from the external capacitive load for use with standard Complementary Metal Oxide Semiconductor (CMOS) or Low Voltage Transistor-Transistor Logic (LVTTTL) I/O cells down to 1.8 V. This buffering also redrives the DDC and CEC signals, allowing the use of longer or cheaper HDMI cables with a higher capacitance. The internal hot plug detect module simplifies the application of the HDMI transmitter to control the hot plug signal.

All lines provide appropriate integrated pull-ups and pull-downs for HDMI compliance and backdrive protection to guarantee that HDMI interface signals are not pulled down if the system is powered down or enters Standby mode. Only a single external capacitor is required for operation.

1.2 Features and benefits

- HDMI 2.0 and all backward compatible standards are supported
- 6.0 Gbps TMDS Bit Rate (600 Mcsc TMDS Character Rate) compatible
- Supports UHD 4k (2160p) 60 Hz display modes
- Impedance matched 100 Ω differential transmission line ESD protection for TMDS lines (± 10 Ω). No Printed-Circuit Board (PCB) pre-compensation required
- Simplified flow-through routing utilizing less overall PCB space
- DDC capacitive decoupling between system side and HDMI connector side and buffering to drive cable with high capacitive load (> 700 pF/25 m)



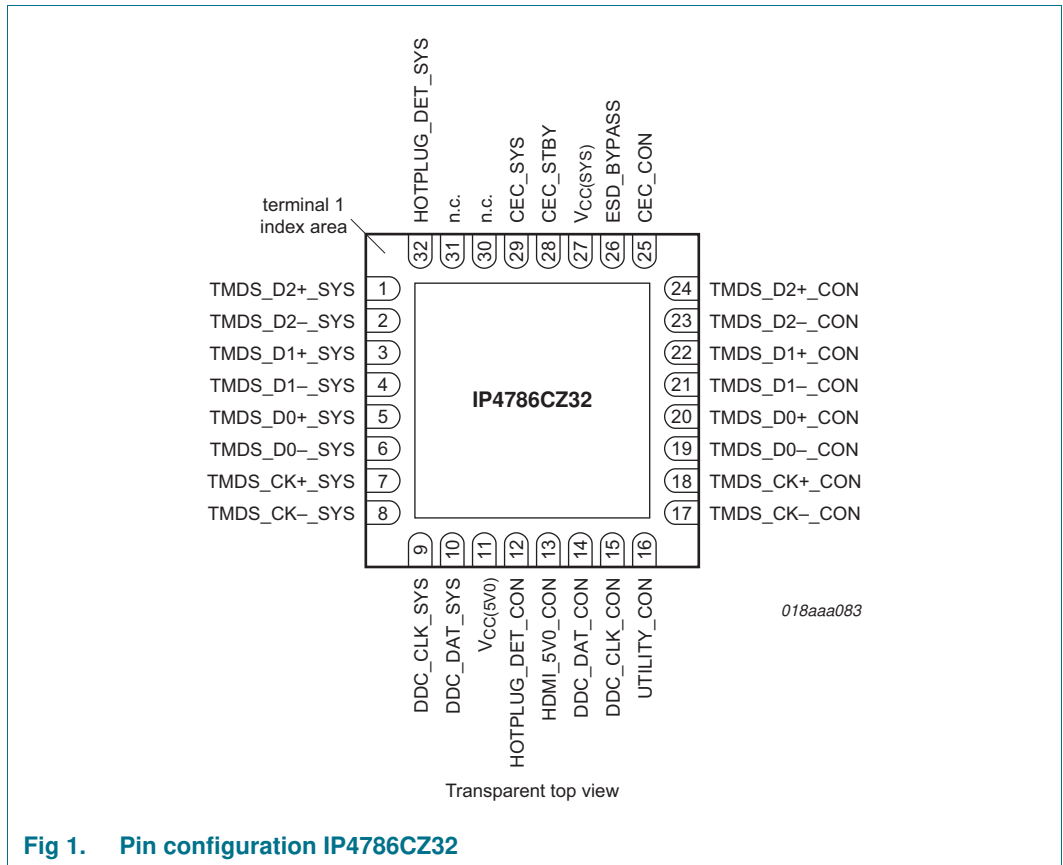
- All external I/O lines with ESD protection of at least ±12 kV, exceeding the IEC 61000-4-2, level 4 standard
- Hot plug detect module
- CEC buffering and isolation, with integrated backdrive-protected 26 kΩ pull-up
- Robust ESD protection without degradation after repeated ESD strikes
- Highest integration in a small footprint, PCB level, optimized RF routing, 32-pin HVQFN leadless package

1.3 Applications

- The IP4786CZ32 can be used for a wide range of HDMI source devices, consumer and computing electronics:
 - ◆ Standard-Definition (SD) and High-Definition (HD) DVD player
 - ◆ Set-top box
 - ◆ PC graphic card
 - ◆ Game console
 - ◆ HDMI picture performance quality enhancer module
 - ◆ Digital Visual Interface (DVI)

2. Pinning information

2.1 Pinning



2.2 Pin description

Table 1. Pin description

Pin	Name	Description
1	TMDS_D2+_SYS	TMDS to ASIC inside system
2	TMDS_D2-_SYS	TMDS to ASIC inside system
3	TMDS_D1+_SYS	TMDS to ASIC inside system
4	TMDS_D1-_SYS	TMDS to ASIC inside system
5	TMDS_D0+_SYS	TMDS to ASIC inside system
6	TMDS_D0-_SYS	TMDS to ASIC inside system
7	TMDS_CK+_SYS	TMDS to ASIC inside system
8	TMDS_CK-_SYS	TMDS to ASIC inside system
9	DDC_CLK_SYS	DDC clock system side
10	DDC_DAT_SYS	DDC data system side
11	V _{CC(5V0)}	5 V supply input
12	HOTPLUG_DET_CON	hot plug detect connector side
13	HDMI_5V0_CON	5 V overcurrent out to connector
14	DDC_DAT_CON	DDC data connector side
15	DDC_CLK_CON	DDC clock connector side
16	UTILITY_CON	utility line ESD protection
17	TMDS_CK-_CON	TMDS ESD protection to connector
18	TMDS_CK+_CON	TMDS ESD protection to connector
19	TMDS_D0-_CON	TMDS ESD protection to connector
20	TMDS_D0+_CON	TMDS ESD protection to connector
21	TMDS_D1-_CON	TMDS ESD protection to connector
22	TMDS_D1+_CON	TMDS ESD protection to connector
23	TMDS_D2-_CON	TMDS ESD protection to connector
24	TMDS_D2+_CON	TMDS ESD protection to connector
25	CEC_CON	CEC signal connector side
26	ESD_BYPASS	ESD bias voltage
27	V _{CC(SYS)}	supply voltage for level shifting
28	CEC_STBY	CEC Standby mode control (LOW for lowest power, CEC-only mode)
29	CEC_SYS	CEC I/O signal system side
30	n.c.	not connected
31	n.c.	not connected
32	HOTPLUG_DET_SYS	hot plug detect system side
ground pad	GND	ground

3. Ordering information

Table 2. Ordering information

Type number	Package		
	Name	Description	Version
IP4786CZ32	HVQFN32	plastic thermal enhanced very thin quad flat package; no leads; 32 terminals; body 5 × 5 × 0.85 mm	SOT617-3

4. Functional diagram

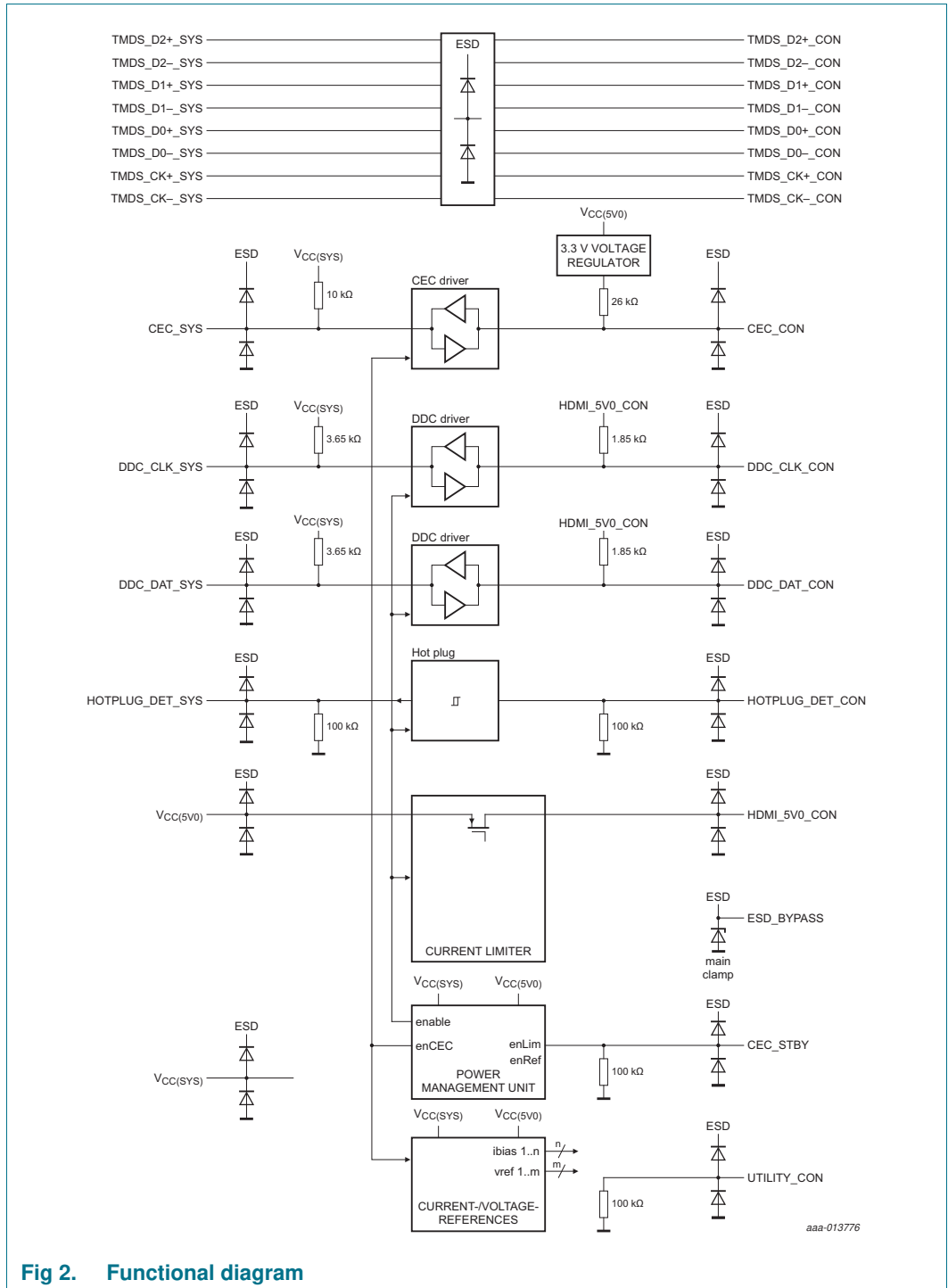


Fig 2. Functional diagram

5. Limiting values

Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC(5V0)}$	supply voltage (5.0 V)		GND – 0.5	6.5	V
V_I	input voltage	I/O pins	GND – 0.5	5.5	V
V_{ESD}	electrostatic discharge voltage	IEC 61000-4-2, level 4 (contact) [1]	-	±12	kV
		IEC 61000-4-2, level 1 (contact) [2]	-	±2	kV
P_{tot}	total power dissipation	DDC operating at 100 kHz; CEC operating at 1 kHz; 50 % duty cycle; CEC_STBY = HIGH; no current at HDMI_5V0_CON	-	50	mW
		DDC and CEC bus in idle mode; CEC_STBY = HIGH; no current at HDMI_5V0_CON	-	3.0	mW
		DDC and CEC bus in idle mode; CEC_STBY = LOW	-	1.0	mW
T_{amb}	ambient temperature		-25	+85	°C
T_{stg}	storage temperature		-55	+125	°C

[1] Connector-side pins (typically denoted with “_CON” suffix) to ground.

[2] System-side pins: CEC_SYS, DDC_DAT_SYS, DDC_CLK_SYS, HOTPLUG_DET_SYS, CEC_STBY, $V_{CC(SYS)}$ and $V_{CC(5V0)}$.

6. Static characteristics

Table 4. Supplies

$T_{amb} = -25\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{CC(5V0)}$	supply voltage (5.0 V)	[1]	4.5	5.0	6.5	V
$V_{CC(SYS)}$	system supply voltage		1.62	3.3	5.5	V

- [1] The IP4786CZ32 contains a 5 V voltage regulator function for higher input voltages. Any input voltage of $4.925\text{ V} < V_{CC(5V0)} < 6.50\text{ V}$ will provide HDMI-compliant output levels of 4.8 V to 5.3 V on HDMI_5V0_CON.

Table 5. TMDS protection circuit

$T_{amb} = -25\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
TMDS channel						
$Z_{i(dif)}$	differential input impedance	TDR measured; $t_r = 200\text{ ps}$	90	100	110	Ω
C_{eff}	effective capacitance	equivalent shunt capacitance for TDR minimum; $t_r = 200\text{ ps}$	[1][2]	0.6	-	pF
Protection diode						
V_{BRzd}	Zener diode breakdown voltage	$I = 1.0\text{ mA}$	6.0	-	9.0	V
r_{dyn}	dynamic resistance	surge; $I = 1.0\text{ A}$; IEC 61000-4-5/9				
		positive transient	-	1.0	-	Ω
		negative transient	-	1.0	-	Ω
		TLP				
		positive transient	[3]	-	1.0	-
	negative transient	[3]	-	1.0	-	Ω
I_{bck}	back current	$V_{CC(5V0)} < V_{ch(TMDS)}$	[4][5]	0.1	1.0	μA
I_{LR}	reverse leakage current	$V_I = 3.0\text{ V}$	-	1.0	-	μA
V_F	forward voltage		-	0.7	-	V
$V_{CL(ch)trt(pos)}$	positive transient channel clamping voltage	100 ns TLP; 50 Ω pulser at 50 ns	-	8.0	-	V

- [1] This parameter is guaranteed by design.
- [2] Capacitive dip at HDMI Time Domain Reflectometer (TDR) measurement conditions.
- [3] ANSI-ESD519.2-2004, ESD sensitivity testing Transmission Line Pulse (TLP) component level method 50 TDR.
- [4] Signal pins:
TMDS_D0+_CON, TMDS_D0-_CON, TMDS_D1+_CON, TMDS_D1-_CON, TMDS_D2+_CON, TMDS_D2-_CON, TMDS_CK+_CON, TMDS_CK-_CON,
TMDS_D0+_SYS, TMDS_D0-_SYS, TMDS_D1+_SYS, TMDS_D1-_SYS, TMDS_D2+_SYS, TMDS_D2-_SYS, TMDS_CK+_SYS and TMDS_CK-_SYS.
- [5] Backdrive current from TMDS_x_SYS and TMDS_x_CON pins to local $V_{CC(5V0)}$ bias rail at power-down. Device does not block backdrive current leakage through the device to/from ASIC I/O pins connected to TMDS_x_SYS pins.

Table 6. HDMI_5V0_CON

$T_{amb} = -25\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
r_{dyn}	dynamic resistance	TLP				
		positive transient [1]	-	1.0	-	Ω
		negative transient [1]	-	1.0	-	Ω
V_{CL}	clamping voltage	100 ns TLP; 50 Ω pulser at 50 ns	-	8	-	V
$I_{O(max)}$	maximum output current	$V_{(HDMI_5V0_CON)} = 4.8\text{ V}$	55	-	-	mA
I_{bck}	back current	$V_{CC(5V0)} < V_{(HDMI_5V0_CON)}$	-	-	10	μA
$I_{O(sc)}$	short-circuit output current	$V_{(HDMI_5V0_CON)} = 0\text{ V}$	-	125	175	mA
V_{do}	dropout voltage	$4.5\text{ V} < V_{CC(5V0)} < 4.925\text{ V}$; DDC = LOW [2]				
		$I_O = 10\text{ mA}$	-	70	-	mV
		$I_O = 55\text{ mA}$	-	-	125	mV
$V_{O(LDO)}$	LDO output voltage	$I_O \leq 55\text{ mA}$; $4.925\text{ V} < V_{CC(5V0)} < 6.5\text{ V}$; DDC = LOW [2]	4.8	5.05	5.3	V

[1] ANSI-ESD519.4-2004, ESD sensitivity testing TLP component level method 50 TDR.

[2] The IP4786CZ32 contains a 5 V voltage regulator function for higher input voltages. Any input voltage of $4.925\text{ V} < V_{CC(5V0)} < 6.50\text{ V}$ will provide HDMI-compliant output levels of 4.8 V to 5.3 V on HDMI_5V0_CON.

Table 7. UTILITY_CON

$T_{amb} = -25\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Supplies: pins $V_{CC(5V0)}$ and $V_{CC(SYS)}$						
r_{dyn}	dynamic resistance	TLP				
		positive transient [1]	-	1.0	-	Ω
		negative transient [1]	-	1.0	-	Ω
V_{CL}	clamping voltage	100 ns TLP; 50 Ω pulser at 50 ns	-	8.0	-	V
C_i	input capacitance	$V_{CC(5V0)} = 0\text{ V}$; $V_{CC(SYS)} = 0\text{ V}$; $V_{bias} = 2.5\text{ V}$; AC input = $3.5\text{ V}_{(p-p)}$; $f = 100\text{ kHz}$	-	8.0	10	pF
R_{pd}	pull-down resistance		60	100	140	k Ω

[1] ANSI-ESD519.4-2004, ESD sensitivity testing TLP component level method 50 TDR.

Table 8. Static characteristics

$T_{amb} = -25\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
DDC buffer on connector side [1]						
V_{IH}	HIGH-level input voltage		$0.5 \times V_{(HDMI_5V0_CON)}$	-	6.5	V
V_{IL}	LOW-level input voltage		-0.5	-	$0.3 \times V_{(HDMI_5V0_CON)}$	V
V_{OH}	HIGH-level output voltage		$V_{(HDMI_5V0_CON)} - 0.02$	-	$V_{(HDMI_5V0_CON)} + 0.02$	V
V_{OL}	LOW-level output voltage	internal pull-up and external sink	-	100	200	mV
V_{IK}	input clamping voltage	$I_I = -18\text{ mA}$	-	-	-1.0	V
C_{IO}	input/output capacitance	$V_{CC(5V0)} = 5.0\text{ V};$ $V_{CC(SYS)} = 3.3\text{ V};$ $CEC_STBY = \text{HIGH}$	-	8.0	10	pF
R_{pu}	pull-up resistance		1.6	1.8	2.0	k Ω
DDC buffer on system side [1][4]						
V_{IH}	HIGH-level input voltage	$V_{CC(SYS)} = 1.8\text{ V}$	450	-	-	mV
		$V_{CC(SYS)} = 2.5\text{ V}$	620	-	-	mV
		$V_{CC(SYS)} = 3.3\text{ V}$	760	-	-	mV
		$V_{CC(SYS)} = 5.0\text{ V}$	800	-	-	mV
V_{IL}	LOW-level input voltage	$V_{CC(SYS)} = 1.8\text{ V}$	-	-	330	mV
		$V_{CC(SYS)} = 2.5\text{ V}$	-	-	380	mV
		$V_{CC(SYS)} = 3.3\text{ V}$	-	-	400	mV
		$V_{CC(SYS)} = 5.0\text{ V}$	-	-	420	mV
V_{OH}	HIGH-level output voltage		$V_{CC(SYS)} - 0.02$	-	$V_{CC(SYS)} + 0.02$	V
V_{OL}	LOW-level output voltage	$V_{CC(SYS)} = 1.8\text{ V}$	-	490	500	mV
		$V_{CC(SYS)} = 2.5\text{ V}$	-	640	690	mV
		$V_{CC(SYS)} = 3.3\text{ V}$	-	685	790	mV
		$V_{CC(SYS)} = 5.0\text{ V}$	-	720	820	mV
V_{IK}	input clamping voltage	$I_I = -18\text{ mA}$	-	-	-1.0	V
C_{IO}	input/output capacitance	$V_{CC(5V0)} = 0\text{ V};$ $V_{CC(SYS)} = 0\text{ V};$ $V_{bias} = 2.5\text{ V};$ AC input = $3.5\text{ V}_{(p-p)}$; $f = 100\text{ kHz}$	-	6.0	8.0	pF
R_{pu}	pull-up resistance		3.2	3.65	4.1	k Ω

Table 8. Static characteristics ...continued
T_{amb} = -25 °C to +85 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
CEC_CON[1]						
V _{IH}	HIGH-level input voltage		2.0	-	-	V
V _{IL}	LOW-level input voltage		-	-	0.80	V
V _{OH}	HIGH-level output voltage		2.88	3.3	3.63	V
V _{OL}	LOW-level output voltage	I _{OL} = 1.5 mA	-	100	200	mV
C _{IO}	input/output capacitance	V _{CC(5V0)} = 0 V; V _{CC(SYS)} = 0 V; V _{bias} = 1.65 V; AC input = 2.5 V _(p-p) ; f = 100 kHz	[2] -	8.0	10	pF
R _{pu}	pull-up resistance		23.4	26.0	28.6	kΩ
I _{leak(CEC)}	CEC leakage current	V _{CC(5V0)} = 0 V; V _{CC(SYS)} = 0 V; CEC_CON connected to 3.63 V via 27 kΩ	-	-	0.1	μA
CEC_SYS[1][4]						
V _{IH}	HIGH-level input voltage	V _{CC(SYS)} = 1.8 V	450	-	-	mV
		V _{CC(SYS)} = 2.5 V	620	-	-	mV
		V _{CC(SYS)} = 3.3 V	760	-	-	mV
		V _{CC(SYS)} = 5.0 V	800	-	-	mV
V _{IL}	LOW-level input voltage	V _{CC(SYS)} = 1.8 V	-	-	330	mV
		V _{CC(SYS)} = 2.5 V	-	-	380	mV
		V _{CC(SYS)} = 3.3 V	-	-	400	mV
		V _{CC(SYS)} = 5.0 V	-	-	420	mV
V _{OH}	HIGH-level output voltage	[2] V _{CC(SYS)} - 0.02	-	V _{CC(SYS)} + 0.02	V	
V _{OL}	LOW-level output voltage	V _{CC(SYS)} = 1.8 V [5]	-	490	500	mV
		V _{CC(SYS)} = 2.5 V [5]	-	640	690	mV
		V _{CC(SYS)} = 3.3 V [5]	-	675	770	mV
		V _{CC(SYS)} = 5.0 V [5]	-	710	800	mV
C _{IO}	input/output capacitance	V _{CC(5V0)} = 0 V; V _{CC(SYS)} = 0 V; V _{bias} = 1.65 V; AC input = 2.5 V _(p-p) ; f = 100 kHz	[2] -	6.0	7.0	pF
R _{pu}	pull-up resistance		8.5	10	11.5	kΩ
HOTPLUG_DET_CON[1]						
V _{IH}	HIGH-level input voltage		2.0	-	-	V
V _{IL}	LOW-level input voltage		-	-	0.8	V
R _{pd}	pull-down resistance		60	100	140	kΩ
C _i	input capacitance	V _{CC(5V0)} = 0 V; V _{CC(SYS)} = 0 V; V _{bias} = 2.5 V; AC input = 3.5 V _(p-p) ; f = 100 kHz	[2] -	8.0	10	pF

Table 8. Static characteristics ...continued
T_{amb} = -25 °C to +85 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
HOTPLUG_DET_SYS ^[1]						
V _{OH}	HIGH-level output voltage	I _{OL} = 1 mA	0.7 × V _{CC(SYS)}	-	-	V
V _{OL}	LOW-level output voltage	I _{OL} = -1 mA	-	200	300	mV
R _{pd}	pull-down resistance		60	100	140	kΩ

- [1] The device is active if the input voltage at pin CEC_STBY is above the HIGH level.
- [2] This parameter is guaranteed by design.
- [3] Capacitive load measured at power-on.
- [4] No external pull-up resistor attached.
- [5] Typical value at T_{amb} = +25 °C.

Table 9. CEC_STBY power management circuit
V_{CC(SYS)} = 1.62 V to 5.5 V; V_{CC(5V0)} = 4.5 V to 6.5 V; GND = 0 V; T_{amb} = -25 °C to +85 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Board side: input pin CEC_STBY ^[1]						
V _{IH}	HIGH-level input voltage	HIGH = active	^[2] 1.2	-	6.5	V
V _{IL}	LOW-level input voltage	LOW = standby	^[3] -0.5	-	0.8	V
R _{pd}	pull-down resistance		60	100	140	kΩ
C _i	input capacitance	V _i = 3 V or 0 V	-	6	7	pF

- [1] The CEC_STBY pin should be connected permanently to V_{CC(5V0)} or V_{CC(SYS)} if no enable control is needed.
- [2] DDC buffers, Hot Plug Detect (HPD) buffer, and HDMI_5V0_CON out enabled; CEC buffer enabled.
- [3] DDC buffers, HPD buffer, and HDMI_5V0_CON out disabled; CEC buffer enabled.

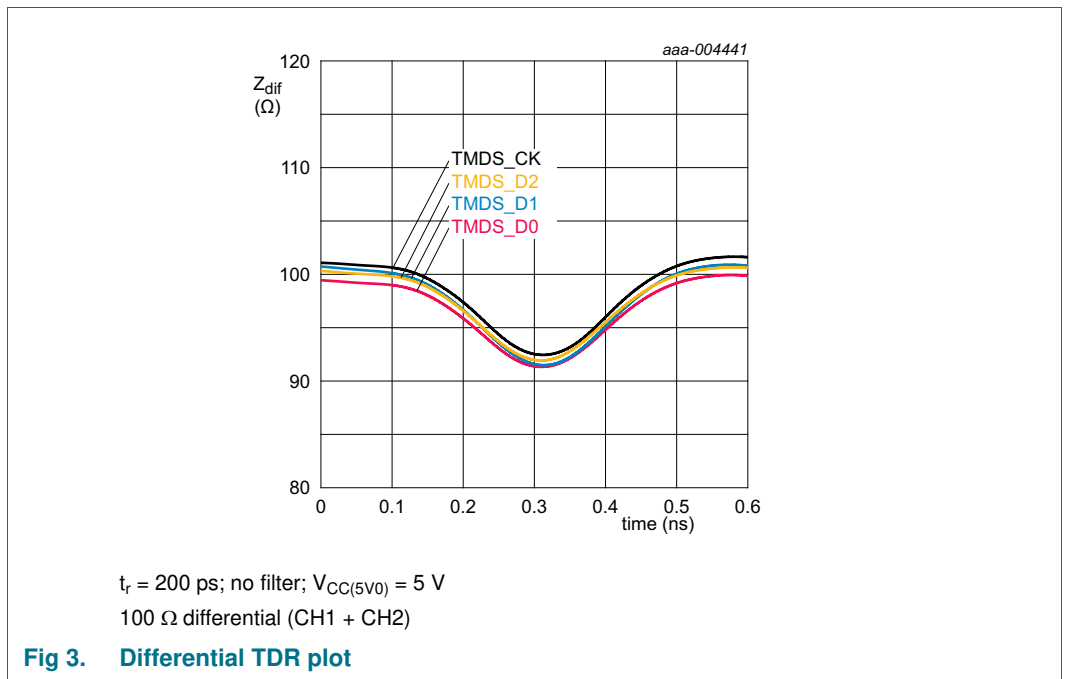
7. Dynamic characteristics

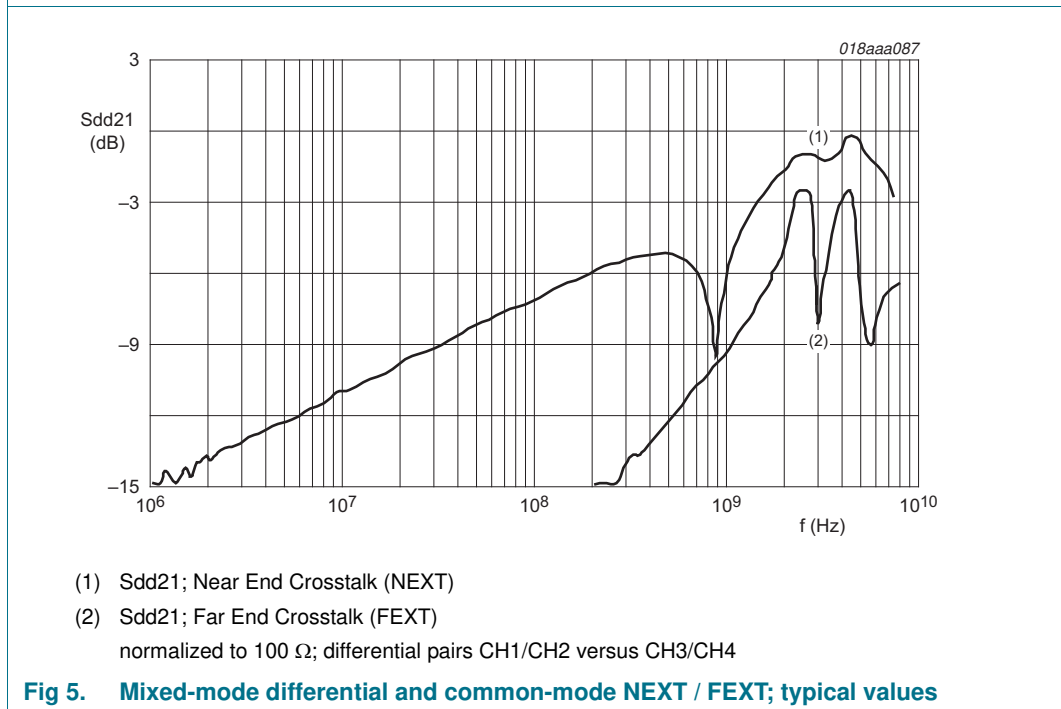
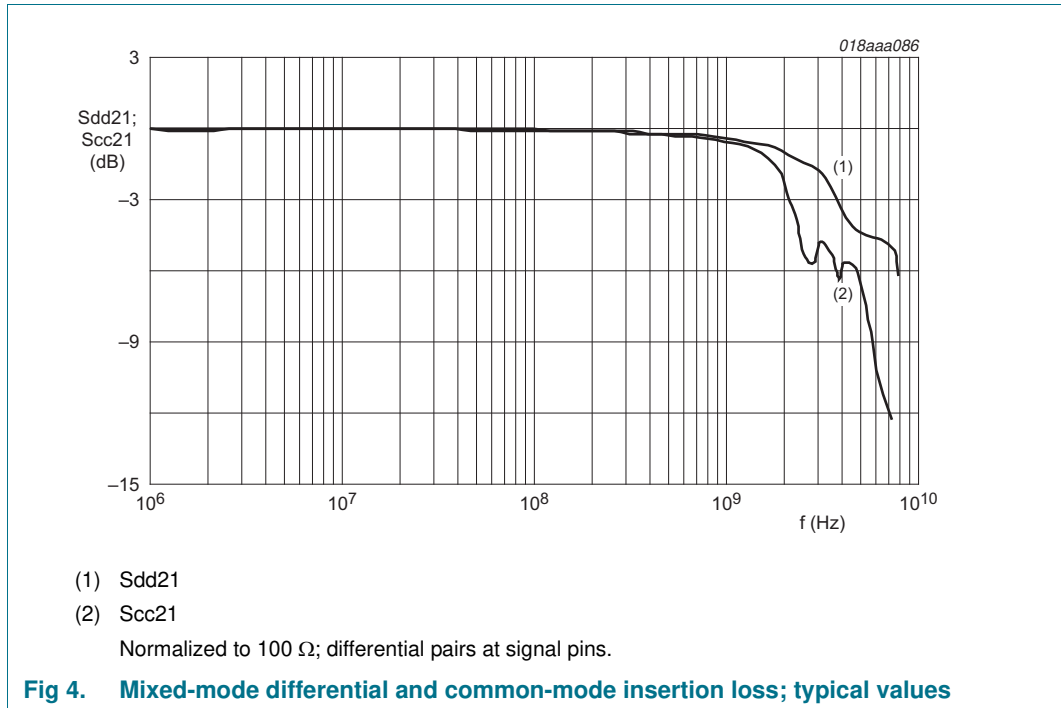
Table 10. Dynamic characteristics

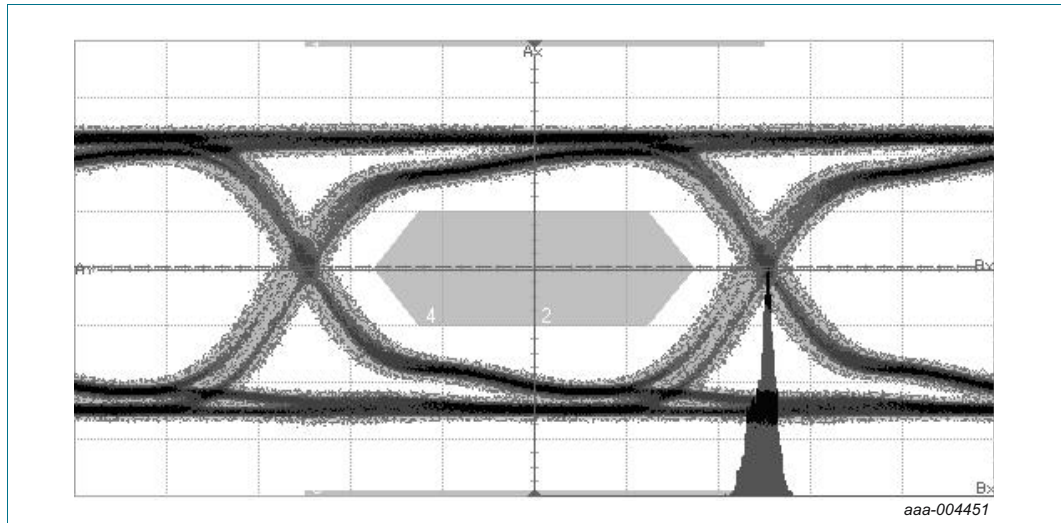
$V_{CC(5V0)} = 5.0\text{ V}$; $V_{CC(SYS)} = 1.8\text{ V}$; $GND = 0\text{ V}$; $T_{amb} = -25\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
DDC_DAT_SYS, DDC_CLK_SYS, DDC_DAT_CON, DDC_CLK_CON^[1]						
t _{PLH}	LOW to HIGH propagation delay	system side to connector side Figure 16	-	80	-	ns
t _{PHL}	HIGH to LOW propagation delay	system side to connector side Figure 16	-	60	-	ns
t _{PLH}	LOW to HIGH propagation delay	connector side to system side Figure 17	-	120	-	ns
t _{PHL}	HIGH to LOW propagation delay	connector side to system side Figure 17	-	80	-	ns
t _{TLH}	LOW to HIGH transition time	connector side Figure 18	-	150	-	ns
t _{THL}	HIGH to LOW transition time	connector side Figure 18	-	100	-	ns
t _{TLH}	LOW to HIGH transition time	system side Figure 19	-	250	-	ns
t _{THL}	HIGH to LOW transition time	system side Figure 19	-	80	-	ns

[1] All dynamic measurements are done with a 75 pF load. Rise times are determined by internal pull-up resistors.

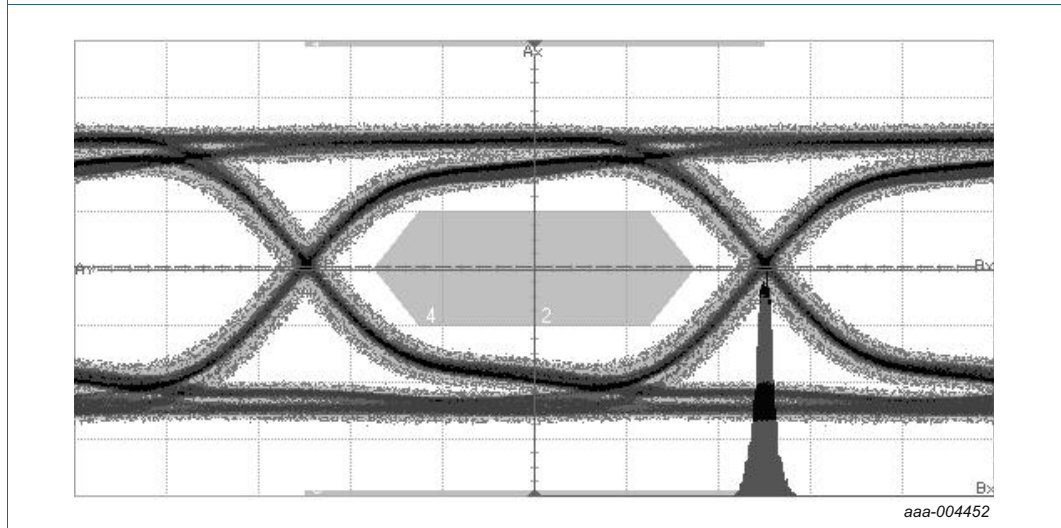






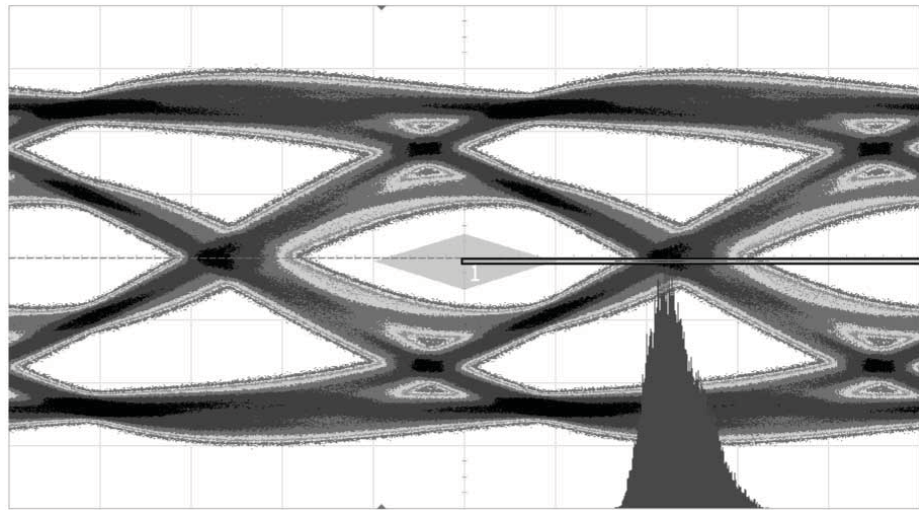
227 MHz pixel clock
 Horizontal scale: 90 ps/div
 Vertical scale: 200 mV/div
 Offset: 42.6 mV

Fig 6. Eye diagram using IP4786CZ32 (1080p, 12 bit)



297 MHz pixel clock
 Horizontal scale: 67.5 ps/div
 Vertical scale: 200 mV/div
 Offset: 42.6 mV

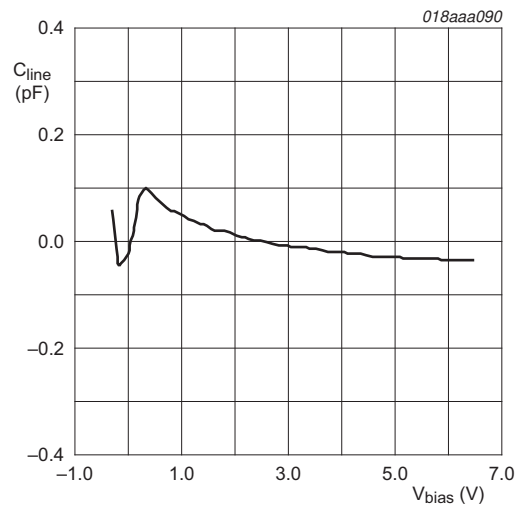
Fig 7. Eye diagram using IP4786CZ32 (1080p, 16 bit)



aaa-013775

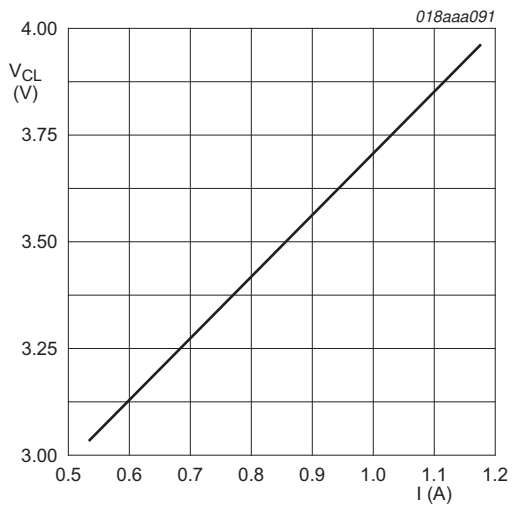
148.5 MHz test frequency
 Horizontal scale: 53.8 ps/div
 Vertical scale: 200 mV/div
 Measured at TP2 with worst cable emulator, reference cable equalizer and worst case negative skew

Fig 8. Eye diagram using IP4786CZ32 (2160p, 60 Hz)



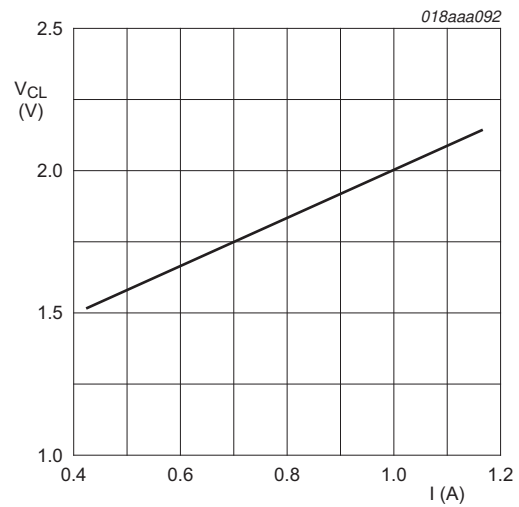
Deviation from typical capacitance normalized at $V_{bias} = 2.5 V$

Fig 9. Line capacitance as a function of bias voltage; typical values



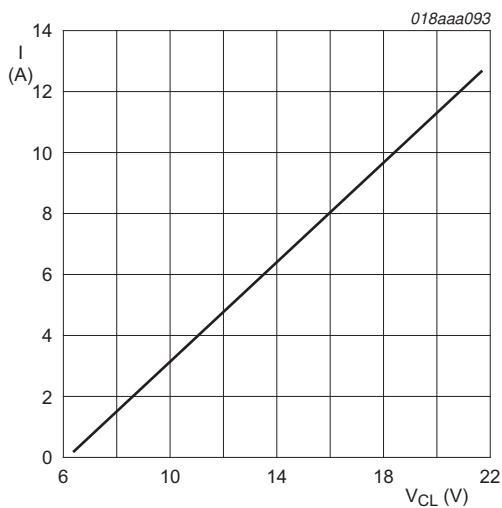
IEC 61000-4-5; $t_p = 8/20 \mu s$; positive pulse

Fig 10. Dynamic resistance with positive clamping



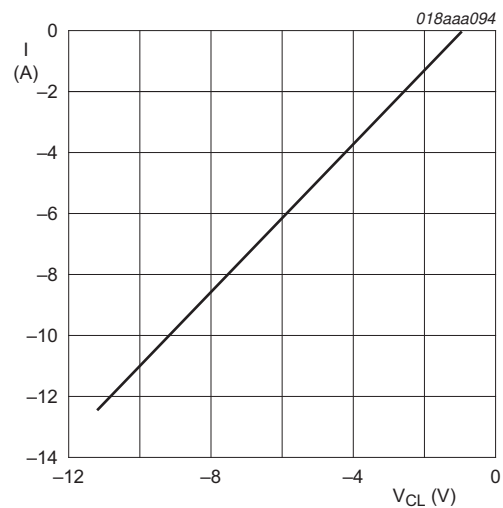
IEC 61000-4-5; $t_p = 8/20 \mu s$; negative pulse

Fig 11. Dynamic resistance with negative clamping



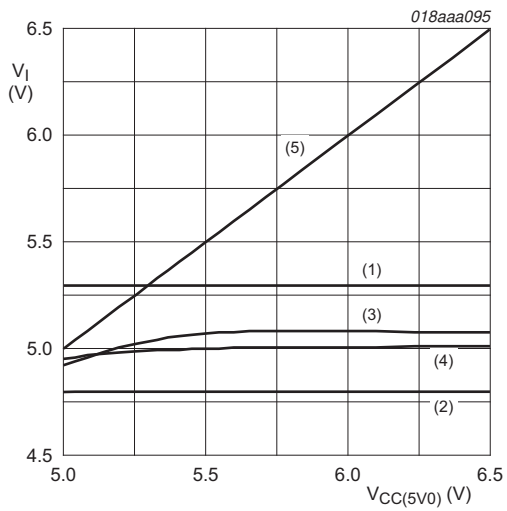
$t_p = 100 ns$; TLP; signal pins; typical values

Fig 12. Dynamic resistance with positive clamping



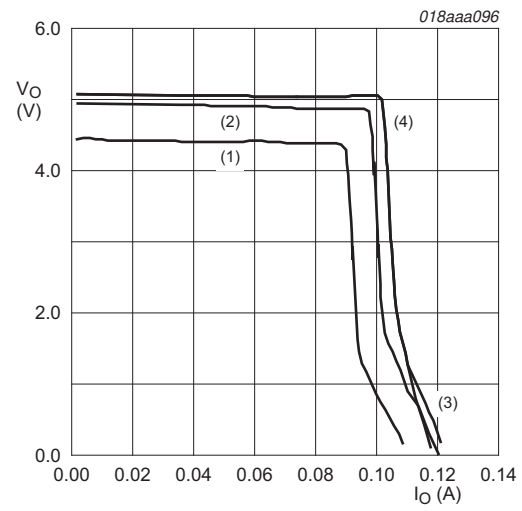
$t_p = 100 ns$; TLP; signal pins; typical values

Fig 13. Dynamic resistance with negative clamping



- (1) 5.3 V; maximum values; HDMI CTS TID 7-11
- (2) 4.8 V; minimum values; HDMI CTS TID 7-11
- (3) $I = 0 \text{ mA}$
- (4) $I = 55 \text{ mA}$
- (5) $V_{CC(5V0)}$ supply input; 4.925 V to 6.5 V

Fig 14. Overvoltage limiter function (HDMI_5V0_CON)



- (1) $V_{CC(5V0)} = 4.5 \text{ V}$
- (2) $V_{CC(5V0)} = 5.0 \text{ V}$
- (3) $V_{CC(5V0)} = 5.5 \text{ V}$
- (4) $V_{CC(5V0)} = 6.5 \text{ V}$

Fig 15. Overcurrent limiter function (HDMI_5V0_CON)

8. AC waveforms

8.1 DDC propagation delay

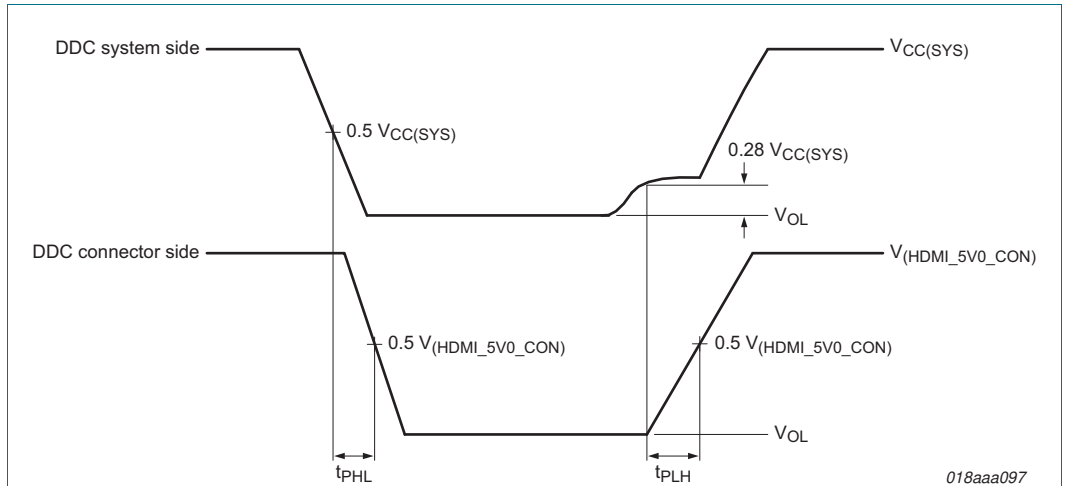


Fig 16. Propagation delay DDC, DDC system side to DDC connector side

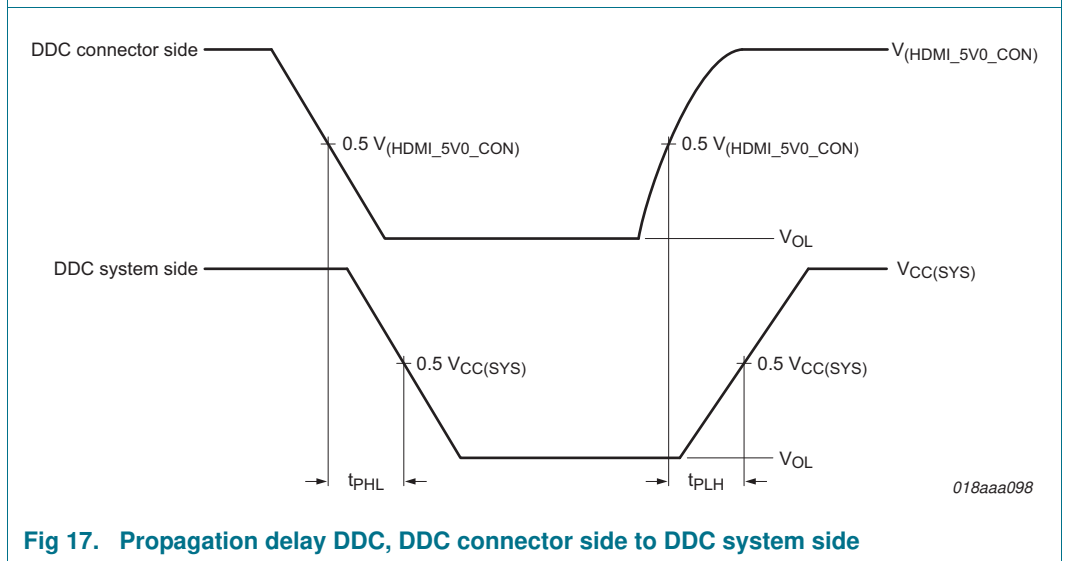


Fig 17. Propagation delay DDC, DDC connector side to DDC system side

8.2 DDC transition time

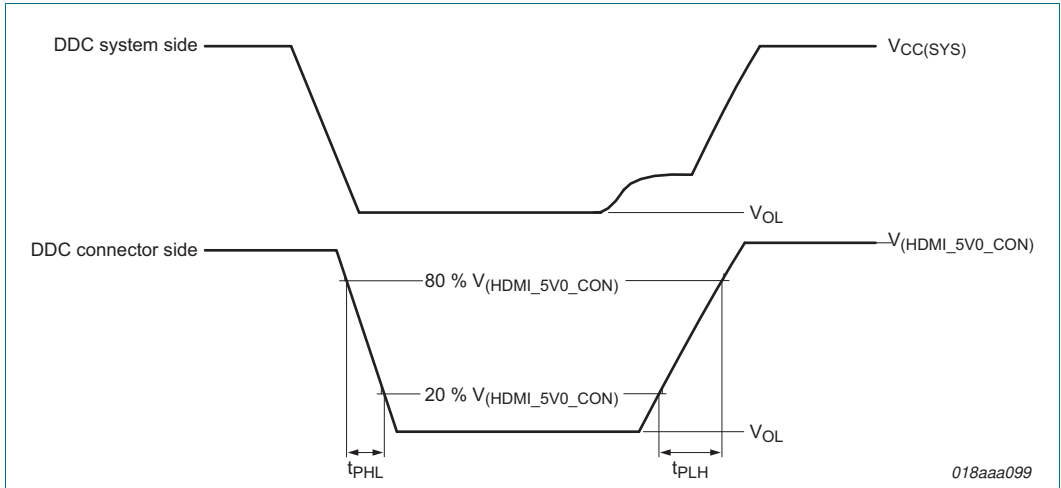


Fig 18. Transition time DDC connector side

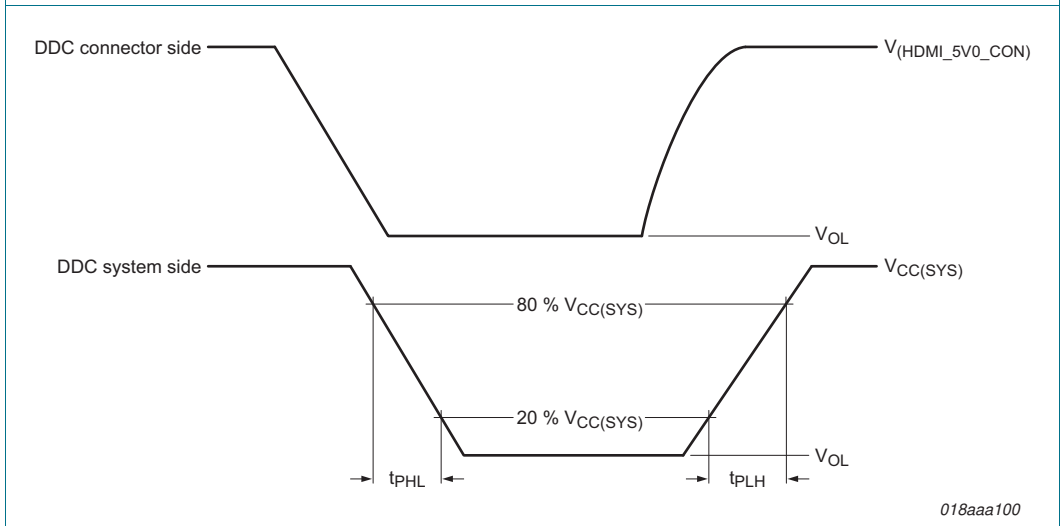


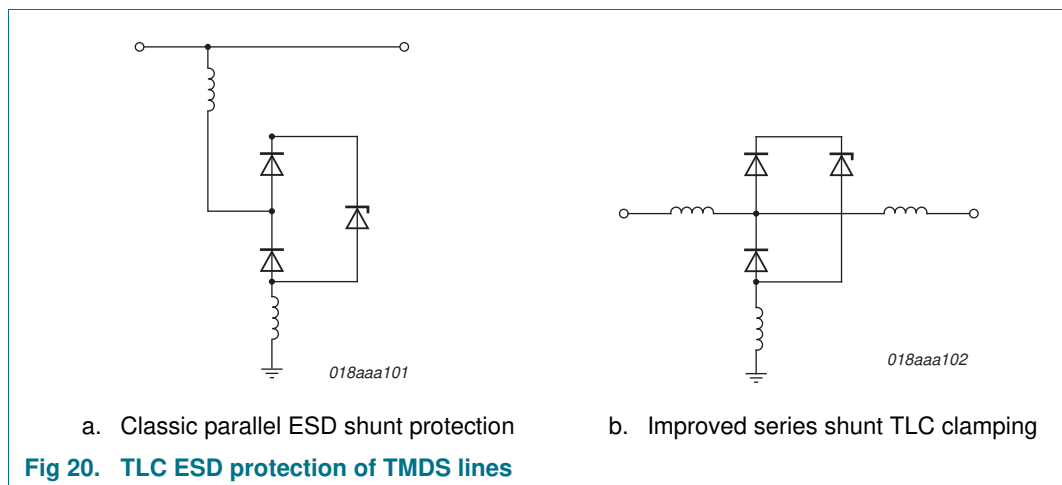
Fig 19. Transition time DDC system side

9. Application information

9.1 TMDS ESD

To protect the TMDS lines and also to comply with the impedance requirements of the HDMI specification, the IP4786CZ32 provides ESD protection with matched TLC ESD structures. Typical Dual Rail Clamp (DRC) or rail-to-rail shunt structures are common for low-capacitance ESD protection (as shown on the left side of [Figure 20](#)) where the dominant factor for the TMDS line impedance dip is determined by the capacitive load to ground. Parasitic lead inductances of the packaging in this case works against the ESD clamping performance by including the $\Delta I/\Delta t$ reactance of the inductance into the path of the ESD shunt.

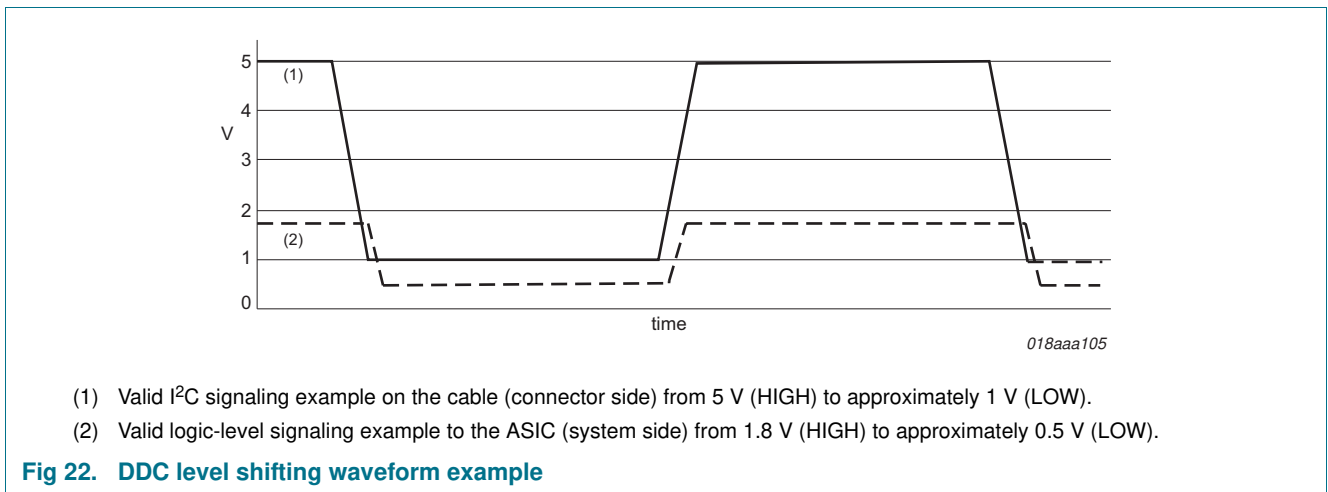
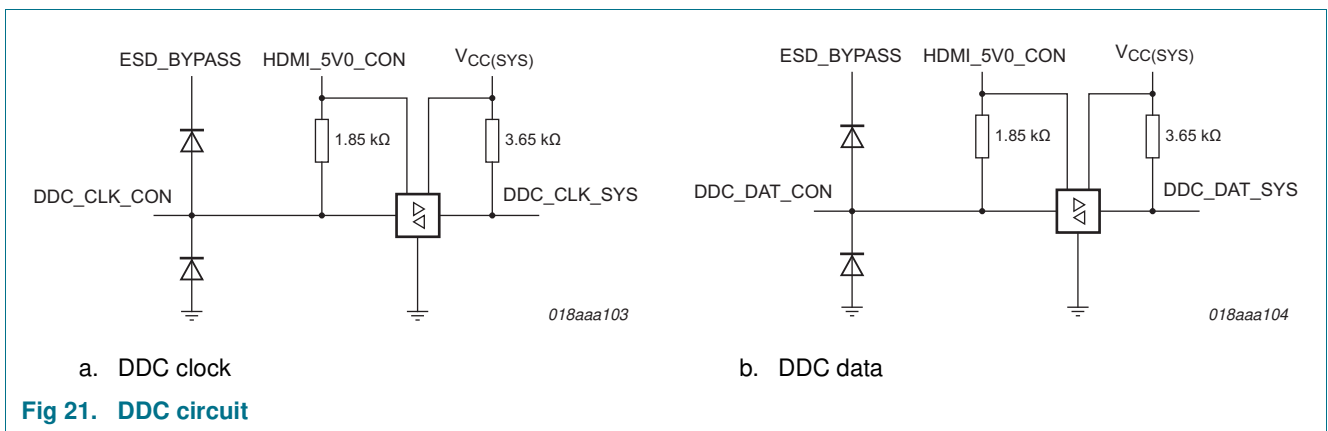
The IP4786CZ32 utilizes these inherent inductances in series with the transmission line in order to present an effective capacitive load of roughly only 0.7 pF. This TLC structure minimizes the capacitive dip, for ideal signal integrity ([Figure 20](#); right side) without complicated PCB pre-compensation. As a beneficial side effect, this enhances the ESD performance of the device as well, since the reactance of the series inductance attenuates the fast initial peak of the ESD pulse, for a lower residual pulse delivered to the Application Specific Integrated Circuit (ASIC).



9.2 DDC circuit

The DDC bus circuit integrates all required pull-ups, and provides full capacitive decoupling between the HDMI connector and the DDC bus lines on the PCB. The capacitive decoupling ensures that the maximum capacitive load is well within the 50 pF maximum of the HDMI specification. No external pull-ups or pull-downs are required.

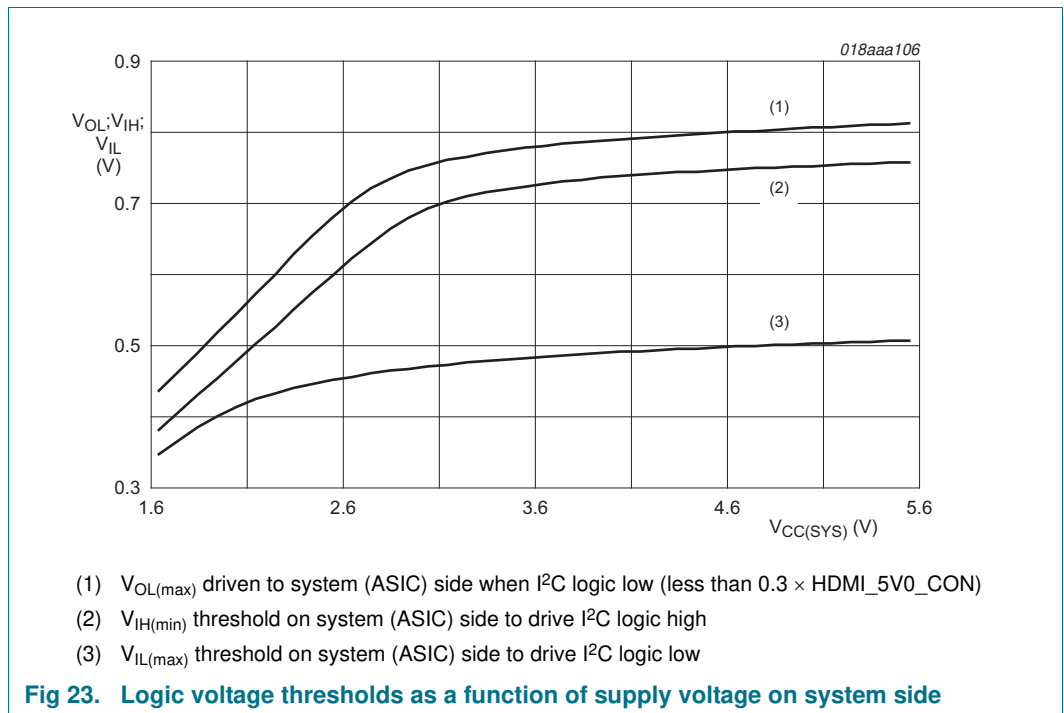
The bidirectional buffers support high-capacitive load on the HDMI cable-side. Various non-compliant but prevalent low-cost cables have been observed with a capacitive load of up to 6 nF on the DDC lines, far exceeding the 700 pF HDMI limit. The IP4786CZ32 can easily decouple this from the weaker ASIC I/O buffers, and drive the rogue cable successfully.



9.3 Logic low I²C voltage shifter

The DDC buffers provide an additional feature commonly required for high-integration HDMI ASICs which are limited to CMOS or LVTTTL LOW-level input voltage (V_{IL}) on their available I/O buffer cells. These I/Os are not strictly compliant with the $0.3 V_{DD}$ threshold voltage levels of I²C and may miss intended logic low levels on the cable between 0.8 V and 1.5 V (typical values).

This feature is also included in the CEC buffer, and thus allows standard I/O buffer cells to be used in ASICs and microcontrollers.



9.4 Hot plug detect circuit and HEAC support

The IP4786CZ32 includes a hot plug detect circuit that simplifies the hot plug application. The circuit generates a standard logic level from the hot plug signal.

The hot plug detect circuit is pulling down the signal to avoid any floating signal. The comparator guarantees a safe detection of the 2 V hot plug signal without any glitches or oscillation at the hot plug output.

The IP4786CZ32 also provides an additional ESD pin to protect the reserved / HEAC pin along with hot plug detect to 12 kV, exceeding IEC 61000-4-2 level 4.

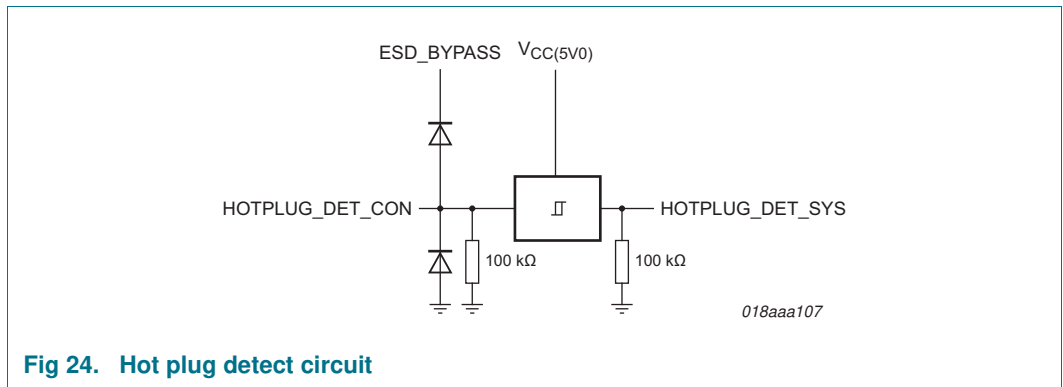


Fig 24. Hot plug detect circuit

9.5 CEC

The logical multidrop topology of the CEC bus can include complex physical stubs, loading cables, and interconnects that may deteriorate signal quality. The IP4786CZ32 includes a full bidirectional buffer to drive the CEC bus and isolate the CEC microcontroller or ASIC General-Purpose Input/Output (GPIO).

The CEC buffer derives power from an on-board 3.3 V regulator from the $V_{CC(5V0)}$ domain (see Figure 25). This allows extensive system power management configurations and guarantees an HDMI-compliant $V_{(CEC_CON)}$ on the connector, as well as the backdrive-protected 125 μ A nominal CEC pull-up which does not degrade the bus when powered down.

By placing the CEC microcontroller and $V_{CC(5V0)}$ input on a 5 V rail as shown in Figure 28, the CEC microcontroller can communicate over CEC for power commands, and then enable the HDMI port via the CEC_STBY pin, as well as the rest of the system as needed.

If IP4786CZ32 Standby modes are not required, or if the Power-down modes are not desired, the CEC_STBY pin can be pulled HIGH to $V_{CC(5V0)}$ or $V_{CC(SYS)}$ for continuous HDMI and CEC operation.

Strapping the CEC_STBY = $V_{CC(SYS)}$ = V_{DD} of ASIC guarantees that all interface signals ending with the suffix “_SYS” on the system side will be disabled when $V_{CC(SYS)}$ goes low, protecting the ASIC I/O signals from exceeding its local V_{DD} . In this mode, even if $V_{CC(5V0)}$ is powered, HDMI_5V0_CON go active and hot plug events can be detected only when the ASIC power supply rail is on.

Strapping CEC_STBY = $V_{CC(5V0)}$ is the most basic configuration where the buffers are enabled whenever the local $V_{CC(5V0)}$ and $V_{CC(SYS)}$ supplies reach minimum operating levels.

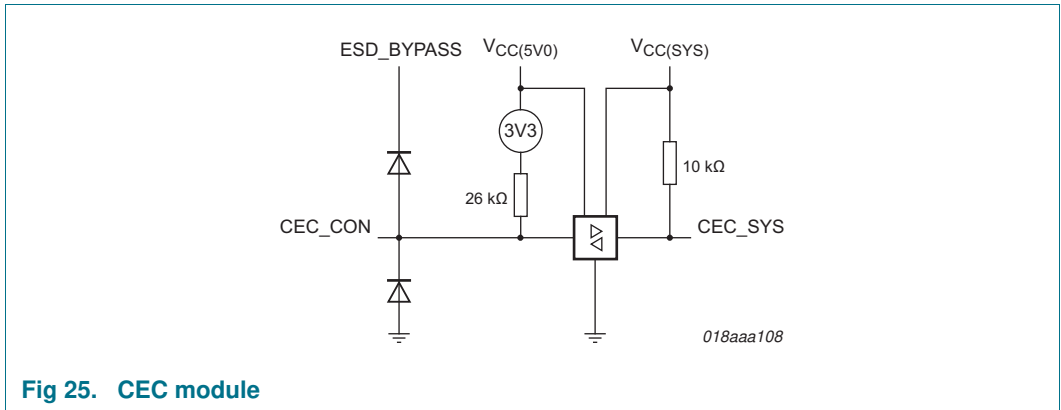


Fig 25. CEC module

9.6 Backdrive protection

The HDMI connector contains various signals which can partly supply current into an HDMI device that is powered down.

Typically, the DDC lines and the CEC signals can force significant current back into the powered-down rails as shown in [Figure 26](#), causing power-on reset problems with the system, and possible damage. The IP4786CZ32 prevents this backdrive condition whenever the I/O voltage is greater than the local supply.

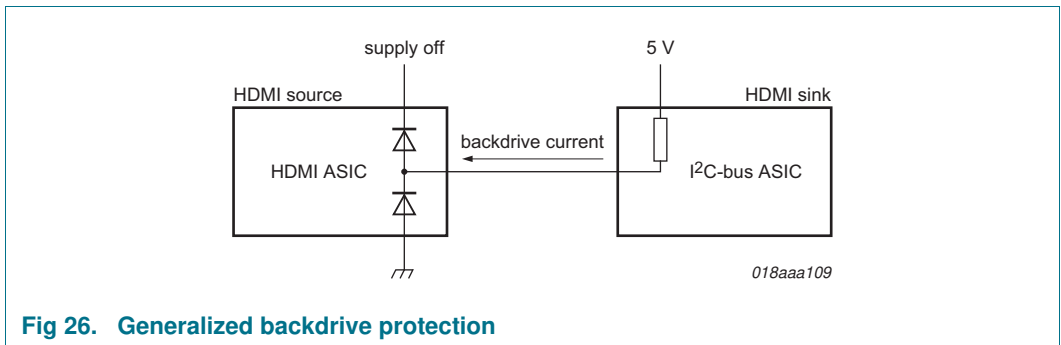


Fig 26. Generalized backdrive protection